## **CLAIMS**

1. A diamond tool fabricated with a single crystal diamond artificially synthesized under high pressure in a temperature difference method, characterized in that said diamond has a crystal containing an impurity in an amount of at most 3 ppm.

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- 2. The diamond tool according to claim 1, wherein said crystal contains said impurity in an amount of at most 0.1 ppm.
- The diamond tool according to claim 1, being one of an ultra high precision cutting tool, a microtome knife, a diamond knife, a diamond stylus, a line drawing die, and a dresser.
- 4. The diamond tool according to claim 1, wherein a titanium containing,
  activated brazing material (22) is employed to attach said diamond to a main body of the tool.
  - 5. A diamond tool fabricated with a single crystal diamond artificially synthesized under high pressure in a temperature difference method, characterized in that said diamond has a crystal containing nitrogen in an amount of at most 3 ppm and also containing nickel.
  - 6. The diamond tool according to claim 5, wherein said nickel is contained in an amount of at least 0.01 ppm and at most 10 ppm.
  - 7. The diamond tool according to claim 5, wherein a titanium containing, activated brazing material (22) is employed to attach said diamond to a main body of the tool.

8. A diamond tool fabricated with a single crystal diamond artificially synthesized under high pressure in a temperature difference method, characterized in that said diamond has a crystal containing nitrogen in an amount of at most 3 ppm and also containing boron and nickel.

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- 9. The diamond tool according to claim 8, wherein said boron is contained in an amount of at least 0.01 ppm and at most 300 ppm.
- 10. The diamond tool according to claim 8, wherein said nickel is contained in an amount of at least 0.01 ppm and at most 10 ppm.
  - 11. The diamond tool according to claim 8, wherein a titanium containing, activated brazing material (22) is employed to attach said diamond to a main body of the tool.
    - 12. A synthetic single crystal diamond synthesized under ultra high pressure at high temperature in a temperature difference method, characterized by having a crystal containing nickel as a substitutional atom.
    - 13. The synthetic single crystal diamond according to claim 12, wherein said nickel is contained in an amount of at least 0.01 ppm and at most 10 ppm.
- 14. The synthetic single crystal diamond according to claim 12, containing nitrogen in an amount of at least 0.01 ppm and at most 3 ppm.
  - 15. The synthetic single crystal diamond according to claim 12, used for a tool.

- 16. The synthetic single crystal diamond according to claim 15, wherein a titanium containing, activated brazing material (22) is employed to attach the synthetic single crystal diamond to an end (23) of said tool.
- 5 17. The synthetic single crystal diamond according to claim 12, used for jewelry.
  - 18. A diamond tool comprising the synthetic single crystal diamond of claim 12.
- 19. Diamond jewelry comprising the synthetic single crystal diamond of claim 12.
  - 20. A method of synthesizing a single crystal diamond under ultra high pressure at high temperature in a temperature difference method, characterized by employing a solvent formed of at least one of iron and cobalt, at least 36% by weight of nickel, at least 1% by weight and at most 2% by weight of titanium, and at least 3% by weight and at most 5.5% by weight of graphite.
- The method according to claim 20, wherein a seed face of a seed crystal (13) is a (100) plane of a crystal of diamond.

- 22. The method according to claim 20, wherein said single crystal diamond is synthesized at  $1380 \pm 25$ °C.
- 25. The method according to claim 20, wherein said single crystal diamond is synthesized at a rate of at least 3.9 mg/hr and at most 4.7 mg/hr.
  - 24. A synthetic single crystal diamond synthesized under ultra high pressure at

high temperature in a temperature difference method, characterized by having a crystal containing boron and nickel as substitutional atoms.

25. The synthetic single crystal diamond according to claim 24, wherein said boron is contained in an amount of at least 1 ppm and at most 300 ppm.

- 26. The synthetic single crystal diamond according to claim 24, wherein said nickel is contained in an amount of at least 0.01 ppm and at most 10 ppm.
- The synthetic single crystal diamond according to claim 24, containing nitrogen in an amount of at most 3 ppm.
  - 28. The synthetic single crystal diamond according to claim 24, used for a tool.
- 15 29. The synthetic single crystal diamond according to claim 28, wherein a titanium containing, activated brazing material (22) is employed to attach the synthetic single crystal diamond to an end (23) of said tool.
- The synthetic single crystal diamond according to claim 24, used for jewelry.
  - 31. A diamond tool comprising the synthetic single crystal diamond of claim 24.
- 32. Diamond jewelry comprising the synthetic single crystal diamond of claim 25 24.
  - 33. A method of synthesizing a single crystal diamond under ultra high pressure at high temperature in a temperature difference method, characterized by

employing a solvent formed of at least one of iron and cobalt, at least 36% by weight of nickel, at least 1% by weight and at most 2% by weight of titanium, at least 0.1% by weight and at most 0.2% by weight of boron and at least 3% by weight and at most 5.5% by weight of graphite.

- 34. The method according to claim 33, wherein a seed face of a seed crystal (13) is a (100) plane of a crystal of diamond.
- 35. The method according to claim 33, wherein said single crystal diamond is synthesized at  $1350 \pm 30^{\circ}$ C.
  - 36. The method according to claim 33, wherein said single crystal diamond is synthesized at a rate of at least 3.1 mg/hr and at most 3.8 mg/hr.